# FAIRCHILD

SEMICONDUCTOR®

# FDB8160\_F085 N-Channel PowerTrench<sup>®</sup> MOSFET

# 30V, 80A, 1.8m $\Omega$

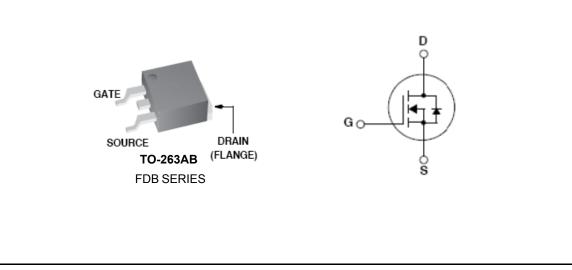
## Features

- Typ  $r_{DS(on)}$  = 1.5m $\Omega$  at V<sub>GS</sub> = 10V, I<sub>D</sub> = 80A
- Typ Q<sub>g(10)</sub> = 187nC at V<sub>GS</sub> = 10V
- Low Miller Charge
- Low Qrr Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

## Applications

- 12V Automotive Load Control
- Starter/Alternator Systems
- Electronic Power Steering Systems
- DC/DC converter





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# **MOSFET Maximum Ratings** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage		30	V	
V <sub>GS</sub>	Gate to Source Voltage		±20	V	
1	Drain Current Continuous (T <sub>C</sub> < 160°C, V <sub>GS</sub> = 10V)		80	А	
D	Pulsed		See Figure 4	A	
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 1)	1290	mJ	
Р	Power Dissipation		254	W	
P <sub>D</sub>	Derate above 25°C		1.7	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to +175	°C	

## **Thermal Characteristics**

$R_{\thetaJC}$	Maximum Thermal Resistance Junction to Case	0.59	°C/W
$R_{\thetaJA}$	Maximum Thermal Resistance Junction to Ambient TO-263,1in <sup>2</sup> copper pad area	43	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8160	FDB8160_F085	TO-263AB	330mm	24mm	800 units

## Electrical Characteristics T<sub>J</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Тур	Мах	Units
Off Cha	racteristics					
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	30	-	-	V
	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 24V, V <sub>GS</sub> = 0V	-	-	1	۸
DSS		T <sub>J</sub> = 150°C	-	-	250	μA
GSS	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA

### **On Characteristics**

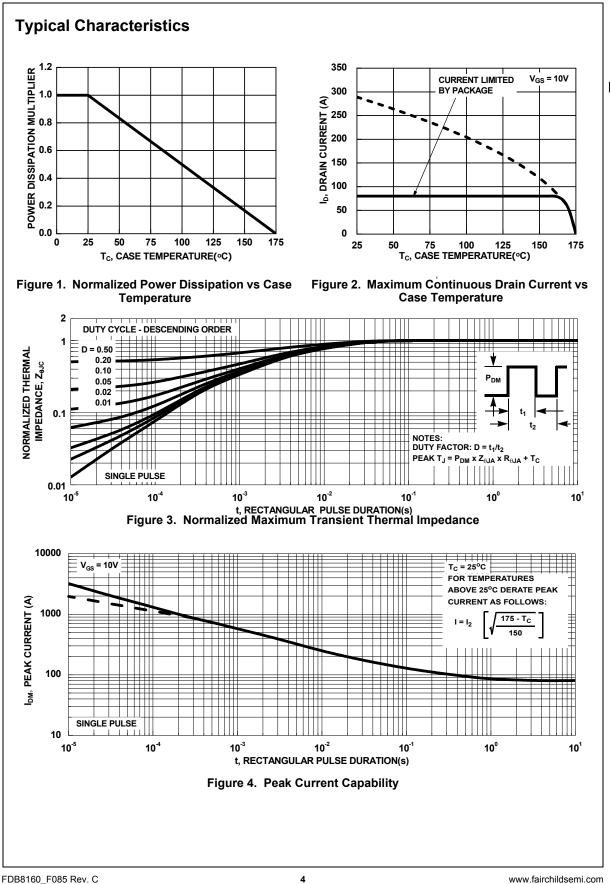
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	2.9	4	V
r	Drain to Source On Resistance	I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V	-	1.5	1.8	mΩ
r <sub>DS(on)</sub>	Drain to Source On Resistance	$I_D$ = 80A, $V_{GS}$ = 10V, $T_J$ = 175°C	-	2.6	3.1	mΩ

### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance		0)/	-	11825	-	pF
C <sub>oss</sub>	Output Capacitance		V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1MHz		1810	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				1240	-	pF
Rg	Gate Resistance	f = 1MHz		-	1.75	-	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V		-	187	243	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 to 2V	V <sub>DD</sub> = 15V	-	20	26	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		I <sub>D</sub> = 80A	-	43	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau			-	23	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	57	-	nC

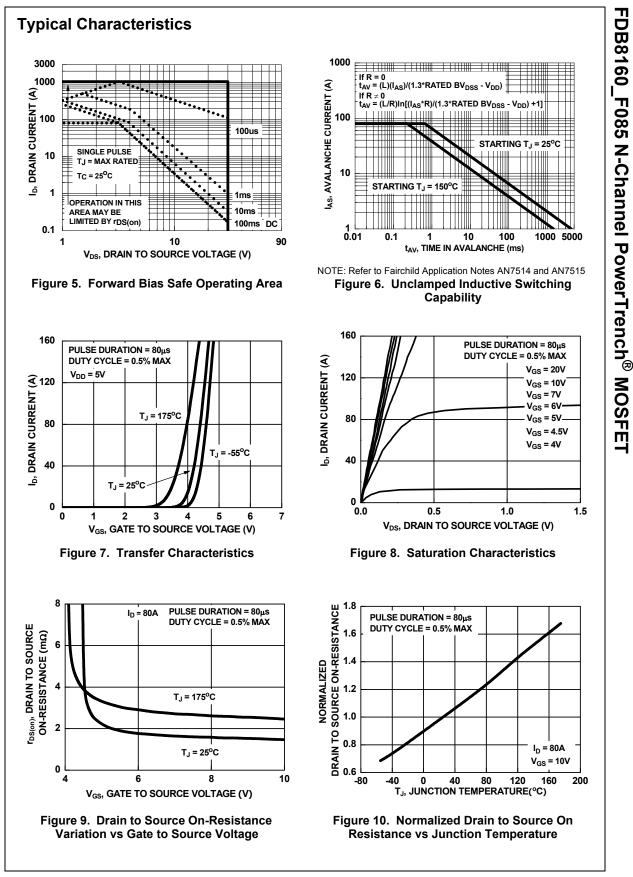
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ymbol	Parameter	Test Conditions	Min	Тур	Max	Units
witch	ing Characteristics					
1	Turn-On Time		-	-	60	ns
on)	Turn-On Delay Time		-	17.2	-	ns
,	Turn-On Rise Time	V <sub>DD</sub> = 15V, I <sub>D</sub> = 80A,	-	18.9	-	ns
off)	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 1.3\Omega$	-	60	-	ns
	Turn-Off Fall Time		-	27	-	ns
:	Turn-Off Time		-	-	137	ns
ain-S	ource Diode Characteristics					
	Source to Drain Diode Voltage	I <sub>SD</sub> = 80A	-	0.9	1.25	V
D	Source to Drain Diode Voltage	I <sub>SD</sub> = 40A	-	0.8	1.0	V
-	Reverse Recovery Time	I <sub>F</sub> = 80A, dI <sub>SD</sub> /dt = 100A/μs	-	48	62	ns
	Reverse Recovery Charge	$I_F = 80A$ , $dI_{SD}/dt = 100A/\mu s$	-	42	55	nC

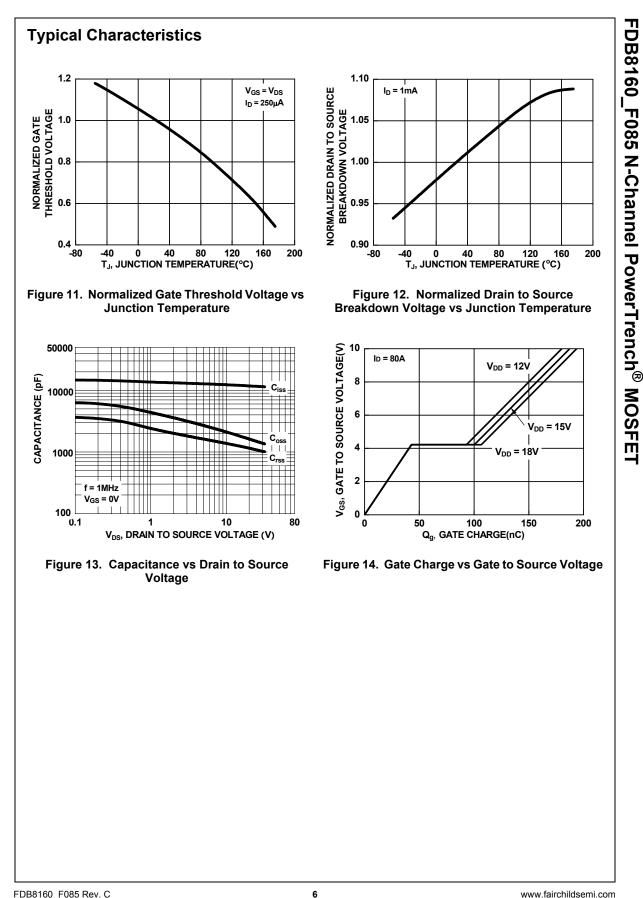


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